

No. 2373

**DFD05T** 

Diffused Junction Type Silicon Diode

0.5A Power Rectifier

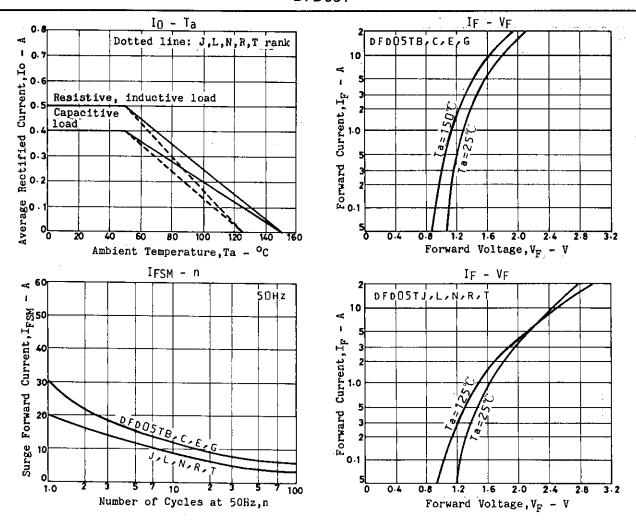
## **Features**

- . High-speed switching use
- . Plastic molded structure
- . Reverse recovery time trr=0.15us max (B,C,E,G) trr=0.3us max (J,L,N,R,T)
- . Peak reverse voltage  $V_{RM}$ =-100 to -1700V . Average rectified current Io=0.5A

Absolute Maximum Ratings at Ta=25°C DFD05TB DFD05TC DFD05TE DFD05TG ur								uni+
Peak Reverse Voltage	$v_{RM}$	_		-100	-200	-400	-600	
Average Rectified Current	Io	Ta=50°C		-100 →	-200 → '	>	0.5	V A
Surge Forward Current	IFSM	50Hz sine wave,		<b>→</b>	<b>→</b>	•••	30	A
Junction Temperature	Тj	1 cycle						0-
Storage Temperature	Tstg			<b>→</b> .	<b>→</b>	~→	150	°C
2001 ago Tompotavate	ISUE						10to+150	°C
		DFDO	5TJ	DFD05TL	DFD05TN	DFD05TR	DFD05TT	unit
Peak Reverse Voltage	$v_{RM}$		800	-1000	-1200	-1500	-1700	V
Average Rectified	Io	Ta=50 <sup>O</sup> C	>	<b>→</b>	<b>→</b>	, . <u>.</u> →	0.5	Ā
Current	_							
Surge Forward Current	IFSM	50Hz		-	<b>→</b> '	<b>→</b>	20	A
current	•	sine wave,						
Junction Temperature	fr: ±	1 cycle						_
Storage Temperature	Tj		<b>→</b>	<b>→</b>	<b>→</b>	<b>-→</b> .	125	°C
boorage remperature	Tstg		<b>→</b>	-	-	1	10to+150	ОС
Electrical Characteristics at Ta=25°C min two max unit								
Forward Voltage			e «ነ			min ty	_	unit
- or war a vortuge	F 7	[ <sub>F</sub> =0.5A(B,C,] [ <sub>F</sub> =0.5A(J,L,]	D,G,	m)			1.2	V
Reverse Current				1)			1.5	V
Reverse Recovery Time	trr 1	$I_R$ : At each $V_{-}=2mA$ $V_{-}=-18$	RM.	8 C F C)			-10	μA
	7	$F=2mA, V_R=-1$	577(J	IIN DT	1		0.15	μs
	-	F-2mr, R1.	) ¥ ( 0	Tenent	,		0.3	μs
2 mA 5 cm Package Dimensions  Reverse Recovery Time Test Circuit (unit: mm) 1174								
Table New York Official								
Unit (resistance: $\Omega$ , capacitance: F)  27.0  27.0  27.0  2.65								

C . Cathode

\_\_\_cathode\_mark\_



- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
  - ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use:
  - ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.